# High Accuracy, Galvanically Isolated Current Sensor IC with Small Footprint SOIC8 Package

#### **FEATURES AND BENEFITS (continued)**

- Output voltage proportional to AC or DC current
- Factory-trimmed sensitivity and quiescent output voltage for improved accuracy
- Chopper stabilization results in extremely stable quiescent output voltage
- Nearly zero magnetic hysteresis
- · Ratiometric output from supply voltage

#### **DESCRIPTION** (continued)

which is compatible with standard lead (Pb) free printed circuit board assembly processes. Internally, the device is Pb-free, except for flip-chip high-temperature Pb-based solder balls, currently exempt from RoHS. The device is fully calibrated prior to shipment from the factory.

#### **SELECTION GUIDE**

Part Number	I <sub>PR</sub> (A)	Sens(Typ) at V <sub>CC</sub> = 3.3 V (mV/A)	T <sub>A</sub> (°C)	Packing <sup>[1]</sup>
ACS722LLCTR-05AB-T [2]	±5	264		
ACS722LLCTR-10AU-T [2]	10	204		
ACS722LLCTR-10AB-T [2]	±10	132		
ACS722LLCTR-20AU-T [2]	20	132	-40 to 150	Tape and Reel, 3000 pieces per reel
ACS722LLCTR-20AB-T [2]	±20	66		
ACS722LLCTR-40AU-T [2]	40	00		
ACS722LLCTR-40AB-T [2]	±40	33		

<sup>[1]</sup> Contact Allegro for additional packing options.



<sup>[2]</sup> Variant not intended for automotive applications.

# High Accuracy, Galvanically Isolated Current Sensor IC with Small Footprint SOIC8 Package

### **SPECIFICATIONS**

#### **ABSOLUTE MAXIMUM RATINGS**

Characteristic	Symbol	Notes	Rating	Units
Supply Voltage	V <sub>CC</sub>		6	V
Reverse Supply Voltage	V <sub>RCC</sub>		-0.1	V
Output Voltage	V <sub>IOUT</sub>		25	V
Reverse Output Voltage	V <sub>RIOUT</sub>		-0.1	V
Maximum Continuous Current	I <sub>CMAX</sub>	T <sub>A</sub> = 25°C	65	А
Operating Ambient Temperature	T <sub>A</sub>	Range L	-40 to 150	°C
Junction Temperature	T <sub>J</sub> (max)		165	°C
Storage Temperature	T <sub>stg</sub>		-65 to 165	°C

#### **ISOLATION CHARACTERISTICS**

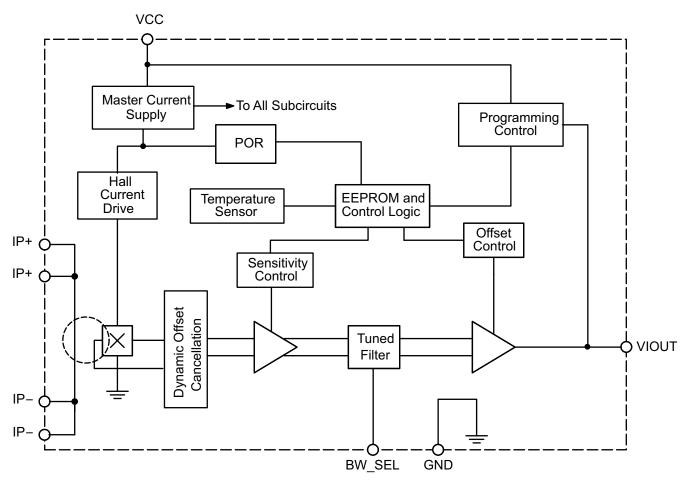
Characteristic	Symbol	Notes	Rating	Unit
Dielectric Strength Test Voltage	V <sub>ISO</sub>	Agency type-tested for 60 seconds per UL 60950-1 (edition. 2). Production tested at V <sub>ISO</sub> for 1 second, in accordance with UL 60950-1 (edition. 2).	2400	V <sub>RMS</sub>
Working Voltage for Regio location	V	Maximum approved working voltage for basic (single)	420	V <sub>PK or</sub> VDC
Working Voltage for Basic Isolation	V <sub>WVBI</sub>	isolation according UL 60950-1 (edition 2).	297	V <sub>RMS</sub>
Clearance	D <sub>cl</sub>	Minimum distance through air from IP leads to signal leads.	3.9	mm
Creepage	D <sub>cr</sub>	Minimum distance along package body from IP leads to signal leads.	3.9	mm

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Test Conditions*		Units
Package Thermal Resistance (Junction to Ambient)	R <sub>θJA</sub>	Mounted on the Allegro 85-0593 evaluation board with 400 mm <sup>2</sup> of 4 oz. copper on each side, connected to pins 1 and 2, and to pins 3 and 4, with thermal vias connecting the layers. Performance values include the power consumed by the PCB.	23	°C/W
Package Thermal Resistance (Junction to Lead)	$R_{\theta JL}$	Mounted on the Allegro ASEK 722 evaluation board.	5	°C/W

 $<sup>{\</sup>rm *Additional\ thermal\ information\ available\ on\ the\ Allegro\ website}.$ 

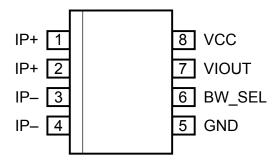




**Functional Block Diagram** 



### PINOUT DIAGRAM AND TERMINAL LIST



**Pinout Diagram** 

#### **TERMINAL LIST TABLE**

Number	Name	Description
1, 2	IP+	Terminals for current being sensed; fused internally
3, 4	IP-	Terminals for current being sensed; fused internally
5	GND	Signal ground terminal
6	BW_SEL	Terminal for selecting 20 kHz or 80 kHz bandwidth
7	VIOUT	Analog output signal
8	VCC	Device power supply terminal



# High Accuracy, Galvanically Isolated Current Sensor IC with Small Footprint SOIC8 Package

# COMMON ELECTRICAL CHARACTERISTICS [1]: Valid through the full range of $T_A = -40^{\circ}\text{C}$ to 150°C, and at $V_{CC} = 3.3$ V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Supply Voltage	V <sub>CC</sub>		3	3.3	3.6	V
Supply Current	I <sub>cc</sub>	V <sub>CC</sub> within V <sub>CC</sub> (min) and V <sub>CC</sub> (max)	_	9	12	mA
Output Capacitance Load	C <sub>L</sub>	VIOUT to GND	_	_	10	nF
Output Resistive Load	R <sub>L</sub>	VIOUT to GND	4.7	_	_	kΩ
Primary Conductor Resistance	R <sub>IP</sub>	T <sub>A</sub> = 25°C	_	0.65	_	mΩ
Magnetic Coupling Factor	C <sub>F</sub>		_	10	_	G/A
Dies Times		$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to GND	_	4	_	μs
Rise Time	t <sub>r</sub>	$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to VCC	_	17.5	_	μs
Propagation Polary		$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to GND	_	1	_	μs
Propagation Delay	t <sub>pd</sub>	$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to VCC	_	5	_	μs
_		$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to GND	_	5	_	μs
Response Time	t <sub>RESPONSE</sub>	$I_P = I_P(max), T_A = 25$ °C, $C_L = 1$ nF, BW_SEL tied to VCC	_	22.5	_	μs
Internal Bandwidth	BWi	Small signal –3 dB; C <sub>L</sub> = 1 nF, BW_SEL tied to GND	_	80	_	kHz
internal bandwidth	DVVI	Small signal –3 dB; C <sub>L</sub> = 1nF, BW_SEL tied to VCC	_	20	_	kHz
Noise Density	I <sub>ND</sub>	Input referenced noise density; T <sub>A</sub> = 25°C, C <sub>L</sub> = 1 nF	_	150	_	μA <sub>(rms)</sub> / √Hz
Naisa		Input referenced noise; BWi = 80 kHz, T <sub>A</sub> = 25°C, C <sub>L</sub> = 1 nF	_	42	_	mA <sub>(rms)</sub>
Noise	I <sub>N</sub>	Input referenced noise; BWi = 20 kHz, T <sub>A</sub> = 25°C, C <sub>L</sub> = 1 nF	_	21	_	mA <sub>(rms)</sub>
Nonlinearity	E <sub>LIN</sub>	Through full range of I <sub>P</sub>	_	±1		%
Saturation Voltage [2]	V <sub>OH</sub>	R <sub>L</sub> = 4.7 kΩ, T <sub>A</sub> = 25°C	V <sub>CC</sub> - 0.33	_	_	V
	V <sub>OL</sub>	$R_L = 4.7 \text{ k}\Omega, T_A = 25^{\circ}\text{C}$	_	_	0.33	V
Power-On Time	t <sub>PO</sub>	Output reaches 90% of steady-state level, $T_A = 25^{\circ}C$ , $I_P = I_{PR}(max)$ applied	_	64		μs

<sup>[1]</sup> Device may be operated at higher primary current levels,  $I_p$ , ambient temperatures,  $T_A$ , and internal leadframe temperatures, provided the Maximum Junction Temperature,  $T_J(max)$ , is not exceeded.



<sup>[2]</sup> The sensor IC will continue to respond to current beyond the range of I<sub>p</sub> until the high or low saturation voltage; however, the nonlinearity in this region will be worse than through the rest of the measurement range.

# High Accuracy, Galvanically Isolated Current Sensor IC with Small Footprint SOIC8 Package

# xLLCTR-5AB PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A$ = -40°C to 150°C, $V_{CC}$ = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
NOMINAL PERFORMANCE				,		1
Current Sensing Range	I <sub>PR</sub>		<b>–</b> 5	_	5	А
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	_	264	_	mV/A
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Bidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.5	-	V
ACCURACY PERFORMANC	E		`			
Concitivity From	E <sub>sens</sub>	T <sub>A</sub> = 25°C to 150°C; measured at I <sub>P</sub> = I <sub>PR</sub> (max)	-2	_	2	%
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	_	±2.5	_	%
Official Vallegia [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-15	_	15	mV
Offset Voltage [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±20	_	mV
Tatal Outroot Francis	_	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2.5	_	2.5	%
Total Output Error [2]	E <sub>TOT</sub>	$I_P = I_{PR}(max), T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%
LIFETIME DRIFT CHARACT	ERISTICS					
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		_	±2	_	%

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.



<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{pR}(max)$ .

# xLLCTR-10AU PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A$ = -40°C to 150°C, $V_{CC}$ = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
NOMINAL PERFORMANCE			*			
Current Sensing Range	I <sub>PR</sub>		0	_	10	А
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	_	264	_	mV/A
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Unidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.1	_	V
ACCURACY PERFORMANO	E					
Canality ity Fran	E <sub>sens</sub>	$T_A = 25$ °C to 150°C; measured at $I_P = I_{PR}(max)$	-2	_	2	%
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	_	±2.5	_	%
Offset Voltage [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-15	_	15	mV
Offset Voltage [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±20	_	mV
Total Outrout Francis[2]	_	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2.5	_	2.5	%
Total Output Error [2]	E <sub>TOT</sub>	$I_{P} = I_{PR}(max), T_{A} = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	-	%
LIFETIME DRIFT CHARACT	ERISTICS					
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		_	±2	_	%

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.

# xLLCTR-10AB PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A = -40^{\circ}$ C to 150°C, $V_{CC} = 3.3$ V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
NOMINAL PERFORMANCE			*			
Current Sensing Range	I <sub>PR</sub>		-10	_	10	Α
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	_	132	_	mV/A
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Bidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.5	-	V
ACCURACY PERFORMANC	E					
Concitivity From	E <sub>sens</sub>	T <sub>A</sub> = 25°C to 150°C; measured at I <sub>P</sub> = I <sub>PR</sub> (max)	-1.5	_	1.5	%
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	_	±2	_	%
Off at 1/alta a [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-10	_	10	mV
Offset Voltage [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±15	_	mV
Tatal Output Fores [2]	_	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2	_	2	%
Total Output Error [2]	E <sub>TOT</sub>	$I_P = I_{PR}(max), T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%
LIFETIME DRIFT CHARACT	ERISTICS					
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		_	±2	_	%

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.



<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{PR}(max)$ .

<sup>[2]</sup> Percentage of  $I_P$ , with  $I_P = I_{PR}(max)$ .

# xLLCTR-20AU PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A$ = -40°C to 150°C, $V_{CC}$ = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
NOMINAL PERFORMANCE						
Current Sensing Range	I <sub>PR</sub>		0	_	20	А
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	_	132	_	mV/A
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Unidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.1	-	V
ACCURACY PERFORMANO	E					
Considiuity Error	E <sub>sens</sub>	$T_A = 25$ °C to 150°C; measured at $I_P = I_{PR}(max)$	-1.5	_	1.5	%
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	_	±2	_	%
Office to Voltage [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-10	_	10	mV
Offset Voltage [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±15	_	mV
Total Outrout Francis[2]	_	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2	_	2	%
Total Output Error [2]	E <sub>TOT</sub>	$I_{P} = I_{PR}(max), T_{A} = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%
LIFETIME DRIFT CHARACT	ERISTICS					
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		-	±2	_	%

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.

# xLLCTR-20AB PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A$ = -40°C to 150°C, $V_{CC}$ = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units				
NOMINAL PERFORMANCE										
Current Sensing Range	I <sub>PR</sub>		-20	_	20	Α				
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	_	66	_	mV/A				
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Bidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.5	-	V				
ACCURACY PERFORMANC	E									
Consitivity From	E <sub>sens</sub>	T <sub>A</sub> = 25°C to 150°C; measured at I <sub>P</sub> = I <sub>PR</sub> (max)	-1.5	_	1.5	%				
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	-	±2	_	%				
Office to Violence [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-10	_	10	mV				
Offset Voltage [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±15	_	mV				
Total Output Error [2]	Г	I <sub>P</sub> = I <sub>PR</sub> (max), T <sub>A</sub> = 25°C to 150°C	-2	_	2	%				
Total Output Error [2]	E <sub>TOT</sub>	$I_P = I_{PR}(max), T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%				
LIFETIME DRIFT CHARACT	ERISTICS									
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%				
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		-	±2	_	%				

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.



<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{pR}(max)$ .

<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{pR}(max)$ .

# xLLCTR-40AU PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A = -40$ °C to 150°C, $V_{CC} = 3.3$ V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
NOMINAL PERFORMANCE			`			
Current Sensing Range	I <sub>PR</sub>		0	_	40	Α
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	-	66	_	mV/A
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Unidirectional; I <sub>P</sub> = 0 A	_	V <sub>CC</sub> × 0.1	-	V
ACCURACY PERFORMANC	E					
Consitiuity Fran	E <sub>sens</sub>	T <sub>A</sub> = 25°C to 150°C; measured at I <sub>P</sub> = I <sub>PR</sub> (max)	-1.5	_	1.5	%
Sensitivity Error		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}(max)$	-	±2	_	%
Offerst Veltone [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-10	_	10	mV
Offset Voltage [1]		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	-	±15	_	mV
Tatal Output Fanan [2]	_	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2	_	2	%
Total Output Error [2]	E <sub>TOT</sub>	$I_P = I_{PR}(max), T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%
LIFETIME DRIFT CHARACT	ERISTICS		`			
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		-	±2	_	%

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.

# xLLCTR-40AB PERFORMANCE CHARACTERISTICS: $T_A$ Range L, valid at $T_A$ = -40°C to 150°C, $V_{CC}$ = 3.3 V, unless otherwise specified

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units			
NOMINAL PERFORMANCE									
Current Sensing Range	I <sub>PR</sub>		-40	_	40	Α			
Sensitivity	Sens	$I_{PR}(min) < I_{P} < I_{PR}(max)$	-	33	-	mV/A			
Zero Current Output Voltage	V <sub>IOUT(Q)</sub>	Bidirectional; I <sub>P</sub> = 0 A	-	V <sub>CC</sub> × 0.5	-	V			
ACCURACY PERFORMANCE									
Sensitivity Error	E <sub>sens</sub>	$T_A = 25^{\circ}\text{C}$ to 150°C; measured at $I_P = I_{PR}(\text{max})$	-1.5	_	1.5	%			
		$T_A = -40$ °C to 25°C; ; measured at $I_P = I_{PR}$ (max)	-	±2	-	%			
Offset Voltage [1]	V <sub>OE</sub>	I <sub>P</sub> = 0 A; T <sub>A</sub> = 25°C to 150°C	-10	_	10	mV			
		I <sub>P</sub> = 0 A; T <sub>A</sub> = -40°C to 25°C	_	±15	-	mV			
Total Output Error [2]	E <sub>TOT</sub>	$I_P = I_{PR}(max), T_A = 25^{\circ}C \text{ to } 150^{\circ}C$	-2	_	2	%			
		$I_P = I_{PR}(max), T_A = -40^{\circ}C \text{ to } 25^{\circ}C$	_	±3	_	%			
LIFETIME DRIFT CHARACTERISTICS									
Sensitivity Error Lifetime Drift	E <sub>sens_drift</sub>		_	±2	_	%			
Total Output Error Lifetime Drift	E <sub>tot_drift</sub>		_	±2	_	%			

<sup>[1]</sup> Offset Voltage does not incorporate any error due to external magnetic fields. See section: Impact of External Magnetic Fields.

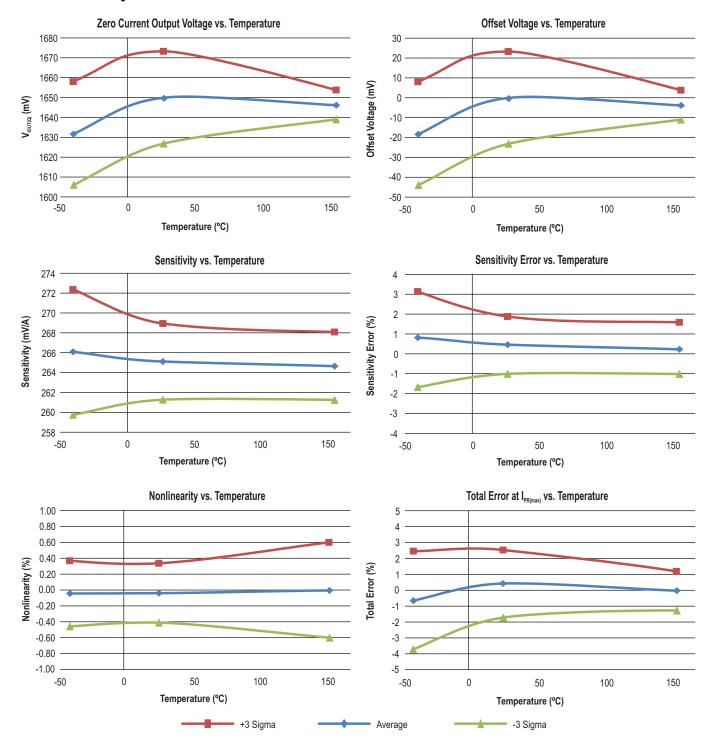


<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{pR}(max)$ .

<sup>[2]</sup> Percentage of  $I_p$ , with  $I_p = I_{PR}(max)$ .

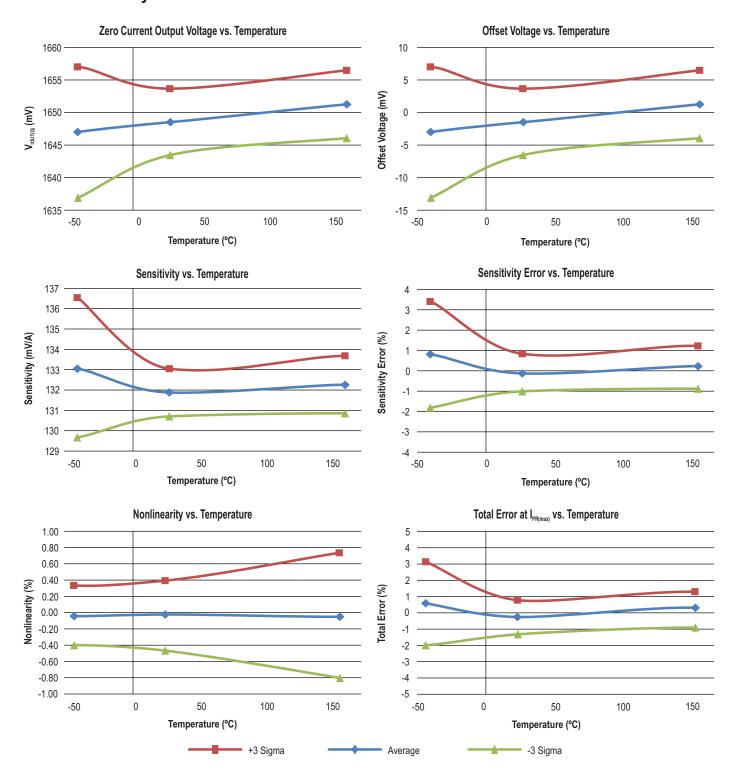
#### CHARACTERISTIC PERFORMANCE

### **xLLCTR-5AB** Key Parameters



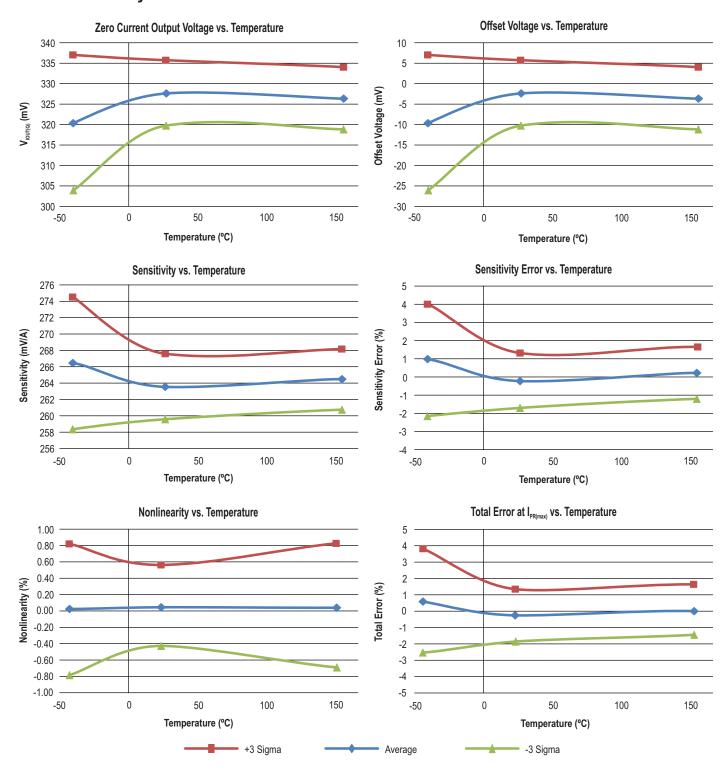


### **xLLCTR-10AB** Key Parameters



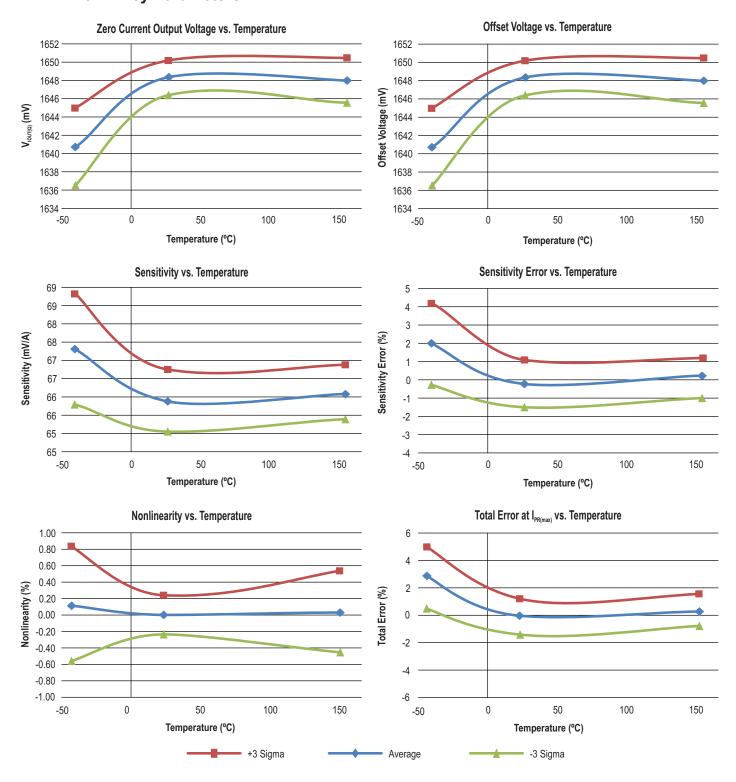


## xLLCTR-10AU Key Parameters



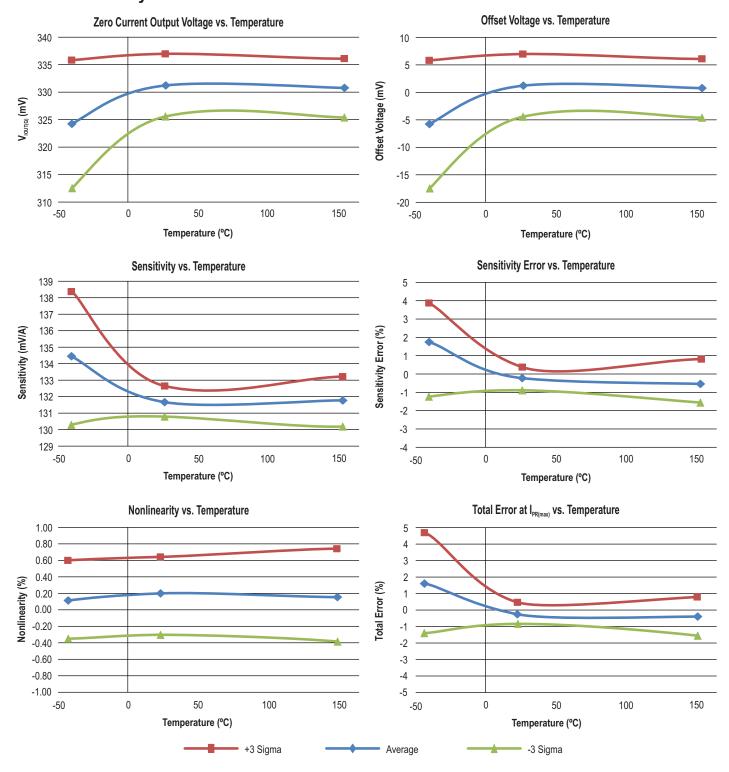


## **xLLCTR-20AB Key Parameters**



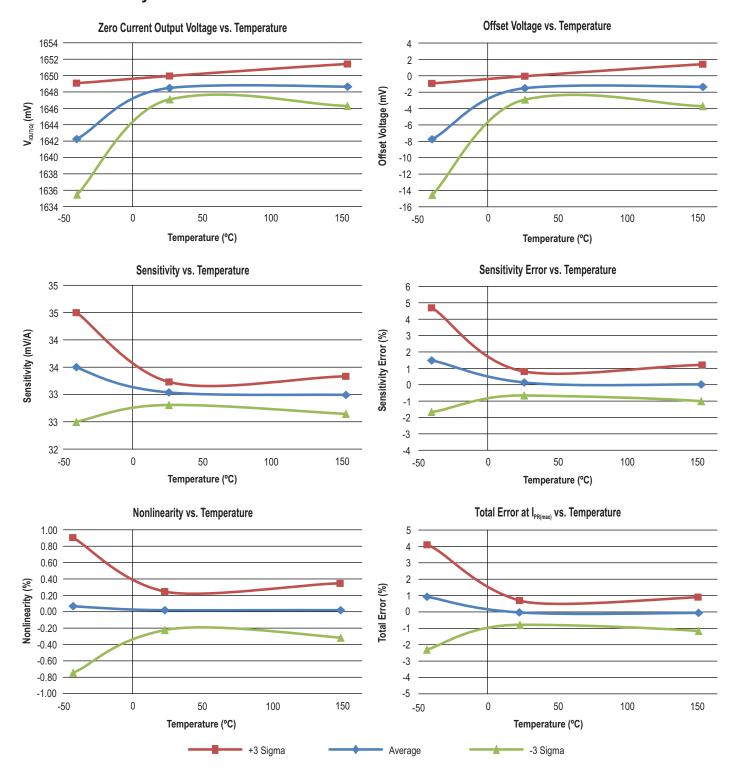


### **xLLCTR-20AU** Key Parameters



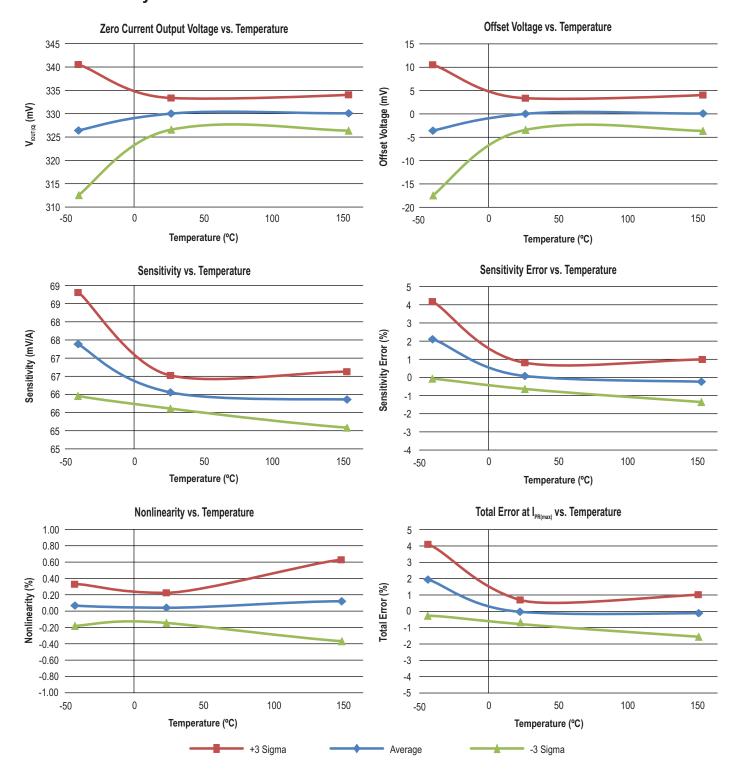


## **xLLCTR-40AB** Key Parameters





### **xLLCTR-40AU** Key Parameters





### **DEFINITIONS OF ACCURACY CHARACTERISTICS**

### Sensitivity (Sens)

The change in sensor IC output in response to a 1 A change through the primary conductor. The sensitivity is the product of the magnetic circuit sensitivity (G/A) (1 G=0.1 mT)and the linear IC amplifier gain (mV/G). The linear IC amplifier gain is programmed at the factory to optimize the sensitivity (mV/A) for the full-scale current of the device.

## Nonlinearity (E<sub>LIN</sub>)

The nonlinearity is a measure of how linear the output of the sensor IC is over the full current measurement range. The nonlinearity is calculated as:

$$E_{LIN} = \left\{ 1 - \left[ \frac{V_{IOUT}(I_{PR}(\text{max})) - V_{IOUT}(Q)}{2 \times V_{IOUT}(I_{PR}(\text{max})/2) - V_{IOUT}(Q)} \right] \right\} \times 100 \text{ (\%)}$$

where  $V_{IOUT}(I_{PR}(max))$  is the output of the sensor IC with the maximum measurement current flowing through it and  $V_{IOUT}(I_{PR}(max)/2)$  is the output of the sensor IC with half of the maximum measurement current flowing through it.

# Zero Current Output Voltage (V<sub>IOUT(Q)</sub>)

The output of the sensor when the primary current is zero. For a unipolar supply voltage, it nominally remains at  $0.5 \times V_{CC}$  for a bidirectional device and  $0.1 \times V_{CC}$  for a unidirectional device. For example, in the case of a bidirectional output device,  $V_{CC} = 3.3 \text{ V}$  translates into  $V_{IOUT(Q)} = 1.65 \text{ V}$ . Variation in  $V_{IOUT(Q)}$  can be attributed to the resolution of the Allegro linear IC quiescent voltage trim and thermal drift.

## Offset Voltage (V<sub>OE</sub>)

The deviation of the device output from its ideal quiescent value of  $0.5 \times V_{CC}$  (bidirectional) or  $0.1 \times V_{CC}$  (unidirectional) due to nonmagnetic causes. To convert this voltage to amperes, divide by the device sensitivity, Sens.

## **Total Output Error (ETOT)**

The difference between the current measurement from the sensor IC and the actual current  $(I_p)$ , relative to the actual current. This is equivalent to the difference between the ideal output voltage and the actual output voltage, divided by the ideal sensitivity, relative to the current flowing through the primary conduction path:

$$E_{\text{TOT}}(I_{\text{P}}) = \frac{V_{\text{IOUT\_ideal}}(I_{\text{P}}) - V_{\text{IOUT}}(I_{\text{P}})}{\text{Sens}_{\text{ideal}}(I_{\text{P}}) \times I_{\text{P}}} \times 100 \text{ (\%)}$$

The Total Output Error incorporates all sources of error and is a function of I<sub>P</sub>. At relatively high currents, E<sub>TOT</sub> will be mostly

due to sensitivity error, and at relatively low currents,  $E_{TOT}$  will be mostly due to Offset Voltage ( $V_{OE}$ ). In fact, at  $I_P = 0$ ,  $E_{TOT}$  approaches infinity due to the offset. This is illustrated in Figures 1 and 2. Figure 1 shows a distribution of output voltages versus  $I_P$  at 25°C and across temperature. Figure 2 shows the corresponding  $E_{TOT}$  versus  $I_P$ .

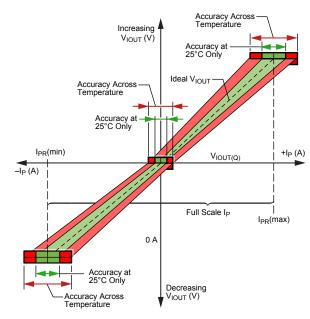


Figure 1: Output Voltage versus Sensed Current

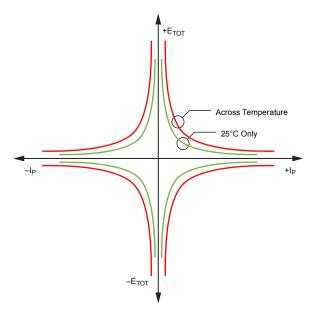


Figure 2: Total Output Error versus Sensed Current



#### APPLICATION INFORMATION

### Impact of External Magnetic Fields

The ACS722 works by sensing the magnetic field created by the current flowing through the package. However, the sensor cannot differentiate between fields created by the current flow and external magnetic fields. This means that external magnetic fields can cause errors in the output of the sensor. Magnetic fields which are perpendicular to the surface of the package affect the output of the sensor, as it only senses fields in that one plane. The error in Amperes can be quantified as:

$$Error(B) = \frac{B}{C_F}$$

where B is the strength of the external field perpendicular to the

surface of the package in Gauss, and  $C_F$  is the coupling factor in G/A. Then, multiplying by the sensitivity of the part, Sens, gives the error in mV.

For example, an external field of 1 Gauss will result in around 0.1 A of error. If the ACS722LLCTR-10AB, which has a nominal sensitivity of 132 mV/A, is being used, that equates to 13.2 mV of error on the output of the sensor.

External Field	Error (A)	Error (mV)				
(Gauss)		5AB	10AB	20AB	40AB	
0.5	0.05	13.2	6.6	3.3	1.65	
1	0.1	26.4	13.2	6.6	3.3	
2	0.2	52.8	26.4	13.2	6.6	



### Thermal Rise vs. Primary Current

Self-heating due to the flow of current should be considered during the design of any current sensing system. The sensor, printed circuit board (PCB), and contacts to the PCB will generate heat as current moves through the system.

The thermal response is highly dependent on PCB layout, copper thickness, cooling techniques, and the profile of the injected current. The current profile includes peak current, current "on-time", and duty cycle. While the data presented in this section was collected with direct current (DC), these numbers may be used to approximate thermal response for both AC signals and current pulses.

The plot in Figure 3 shows the measured rise in steady-state die temperature of the ACS722 versus continuous current at an ambient temperature,  $T_A$ , of 25 °C. The thermal offset curves may be directly applied to other values of  $T_A$ . Conversely, Figure 4 shows the maximum continuous current at a given  $T_A$ . Surges beyond the maximum current listed in Figure 4 are allowed given the maximum junction temperature,  $T_{J(MAX)}$  (165°C), is not exceeded.

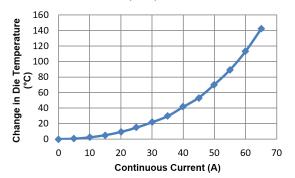


Figure 3: Self-Heating in the LC2 Package

Due to Current Flow

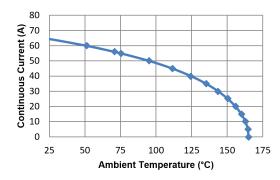


Figure 4: Maximum Continuous Current at a Given T<sub>A</sub>

The thermal capacity of the ACS722 should be verified by the end user in the application's specific conditions. The maximum junction temperature,  $T_{J(MAX)}$  (165°C), should not be exceeded. Further information on this application testing is available in the DC and Transient Current Capability application note on the Allegro website.

### **ASEK722 Evaluation Board Layout**

Thermal data shown in Figure 3 was collected using the ASEK722 Evaluation Board (TED-85-0593-002). This board includes 1388 mm<sup>2</sup> of 4 oz. copper (0.1388) connected to pins 1 and 2, and to pins 3 and 4, with thermal vias connecting the layers. Top and bottom layers of the PCB are shown below in Figure 5.

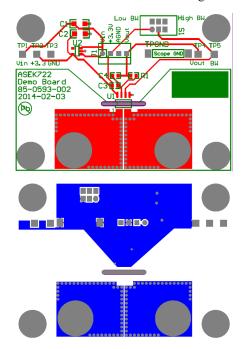


Figure 5: Top and Bottom Layers for ASEK722 Evaluation Board

Gerber files for the ASEK722 evaluation board are available for download from the Allegro website. See the technical documents section of the ACS722 device webpage.



### **DEFINITIONS OF DYNAMIC RESPONSE CHARACTERISTICS**

## Power-On Time (t<sub>PO</sub>)

When the supply is ramped to its operating voltage, the device requires a finite time to power its internal components before responding to an input magnetic field.

Power-On Time,  $t_{PO}$ , is defined as the time it takes for the output voltage to settle within  $\pm 10\%$  of its steady state value under an applied magnetic field, after the power supply has reached its minimum specified operating voltage,  $V_{CC}(\mbox{min})$ , as shown in the chart at right.

## Rise Time (t<sub>r</sub>)

The time interval between a) when the sensor IC reaches 10% of its full scale value, and b) when it reaches 90% of its full scale value. The rise time to a step response is used to derive the bandwidth of the current sensor IC, in which  $f(-3 \text{ dB}) = 0.35/t_r$ . Both  $t_r$  and  $t_{RESPONSE}$  are detrimentally affected by eddy current losses observed in the conductive IC ground plane.

## Propagation Delay (t<sub>pd</sub>)

The propagation delay is measured as the time interval a) when the primary current signal reaches 20% of its final value, and b) when the device reaches 20% of its output corresponding to the applied current.

# Response Time (t<sub>RESPONSE</sub>)

The time interval between a) when the primary current signal reaches 90% of its final value, and b) when the device reaches 90% of its output corresponding to the applied current.

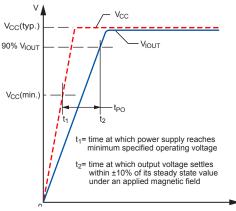


Figure 6: Power-On Time (tpo)

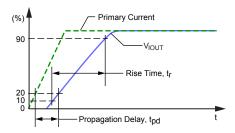


Figure 7: Rise Time (t<sub>r</sub>) and Propagation Delay (t<sub>nd</sub>)

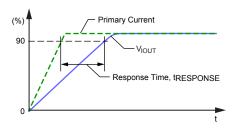


Figure 8: Response Time (t<sub>RESPONSE</sub>)



#### PACKAGE OUTLINE DRAWING

# For Reference Only – Not for Tooling Use (Reference Allegro DWG-0000385, Rev. 2 or JEDEC MS-012AA)

(Reference Allegro DWG-0000385, Rev. 2 or JEDEC MS-012AA)
Dimensions in millimeters – NOT TO SCALE
Dimensions exclusive of mold flash, gate burrs, and dambar protrusions
Exact case and lead configuration at supplier discretion within limits shown

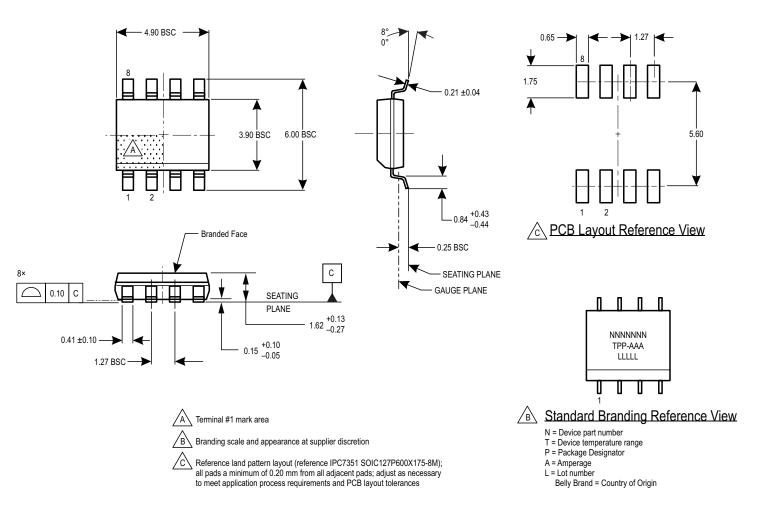


Figure 9: Package LC, 8-pin SOICN



# High Accuracy, Galvanically Isolated Current Sensor IC with Small Footprint SOIC8 Package

#### **REVISION HISTORY**

Number	Date	Description
_	June 10, 2014	Initial release.
1	October 29, 2014	Added Magnetic Coupling Factor characteristic and Error Due to External Magnetic Fields section
2	April 29, 2015	Added Characteristic Performance graphs
3	December 11, 2018	Updated certificate numbers
4	June 3, 2019	Updated TUV certificate mark
5	September 3, 2019	Added Maximum Continuous Current to Absolute Maximum Ratings table (page 3) and thermal data section (page 20)
6	September 9, 2021	Updated package drawing (page 22)

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